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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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N-Channel Power MOSFET

60V, 35A, $22m\Omega$

FEATURES

- Low R_{DS(ON)} to minimize conductive losses
- Low gate charge for fast power switching
- 100% UIS and R_q tested.
- 175°C Operating Junction Temperature
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
V_D	S	60	V	
R _{DS(on)} (max)	$V_{GS} = 10V$	22	mΩ	
Q_g		23	nC	



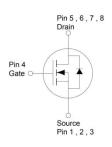




APPLICATIONS

- BLDC Motor Control
- Battery Power Management
- DC-DC converter
- Secondary Synchronous Rectification





Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	60	V	
Gate-Source Voltage		V_{GS}	±20	V	
Oti	$T_C = 25^{\circ}C$		35		
Continuous Drain Current (Note 1)	$T_A = 25^{\circ}C$	I _D	8	_ A	
Pulsed Drain Current		I _{DM}	140	Α	
Single Pulse Avalanche Current (Note 2)		I _{AS}	15	Α	
Single Pulse Avalanche Energy (Note 2)		E _{AS}	33.8	mJ	
Total Davier Dissipation	$T_C = 25^{\circ}C$	В	68	10/	
Total Power Dissipation	T _C = 125°C	P _D	23	W	
Talal Danie Discipality	T _A = 25°C	<u> </u>	3.1	147	
Total Power Dissipation	T _A = 125°C	P _D	1	W	
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +175	°C	

THERMAL PERFORMANCE					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction to Case Thermal Resistance	R _{eJC}	2.2	°C/W		
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	48	°C/W		

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. The $R_{\Theta JA}$ limit presented here is based on mounting on a 1 in² pad of 2 oz copper.

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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static		<u>.</u>				
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	60			V
Gate Threshold Voltage	$V_{GS} = V_{DS}, \ I_D = 250 \mu A$	V _{GS(TH)}	2	3.3	4	V
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
	$V_{GS} = 0V, V_{DS} = 60V$				1	
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 60V$ $T_{J} = 125^{\circ}C$	I _{DSS}			100	μΑ
Drain-Source On-State Resistance (Note 3)	$V_{GS} = 10V, I_D = 8A$	R _{DS(on)}		19	22	mΩ
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 8A$	g _{fs}		35		S
Dynamic (Note 4)		•				
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 30V,$	Q_g		23	-	nC
Gate-Source Charge		Q _{gs}		6.5		
Gate-Drain Charge	$I_D = 8A$	Q_{gd}		5.4		
Input Capacitance		C _{iss}		1454		
Output Capacitance	$V_{GS} = 0V$, $V_{DS} = 30V$	C _{oss}		90		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		24		
Gate Resistance	f = 1.0MHz	R_g	0.6	2	4	Ω
Switching (Note 4)						
Turn-On Delay Time		t _{d(on)}		3		
Turn-On Rise Time	$V_{GS} = 10V, V_{DS} = 30V,$ $I_{D} = 8A, R_{G} = 2\Omega$	t _r		19		
Turn-Off Delay Time		t _{d(off)}		10		ns
Turn-Off Fall Time		t _f		18		
Source-Drain Diode						
Forward Voltage (Note 3)	$V_{GS} = 0V, I_{S} = 8A$	V _{SD}			1.2	V
Reverse Recovery Time	I _S = 8A,	t _{rr}		16		ns
Reverse Recovery Charge	dl/dt = 100A/µs	Q _{rr}		11		nC

Notes:

- 1. Silicon limited current only.
- 2. $L=0.3mH,\ V_{GS}=10V,\ V_{DD}=30V,\ R_G=25\Omega,\ I_{AS}=15A,\ Starting\ T_J=25^{\circ}C$
- 3. Pulse test: Pulse Width \leq 300µs, duty cycle \leq 2%.
- 4. Switching time is essentially independent of operating temperature.

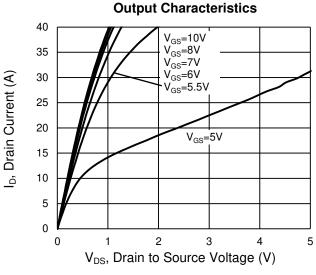
ORDERING INFORMATION

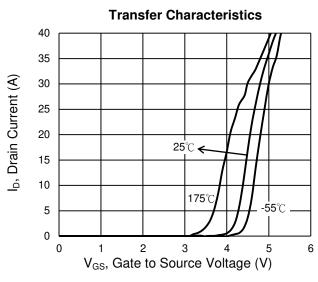
PART NO.	PACKAGE	PACKING
TSM220NB06CR RLG	PDFN56	2,500pcs / 13" Reel

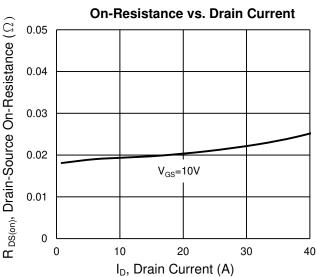


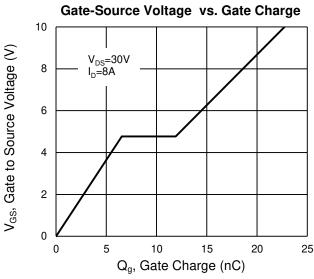
CHARACTERISTICS CURVES

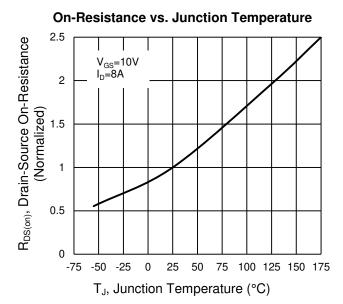
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

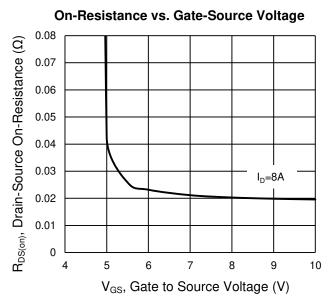










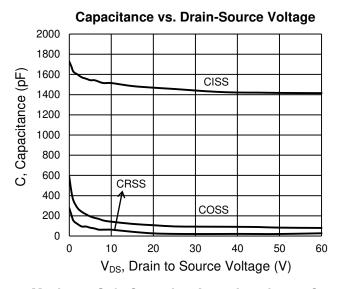


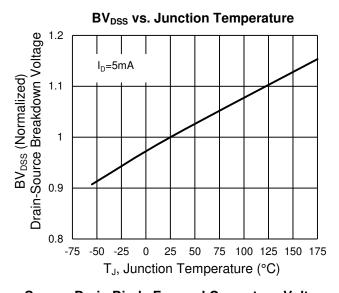
3



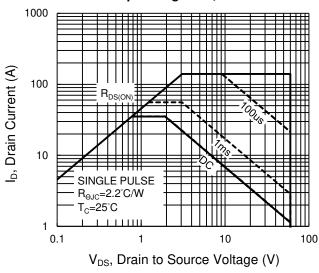
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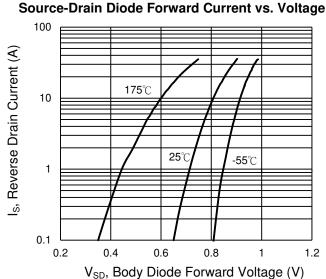
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

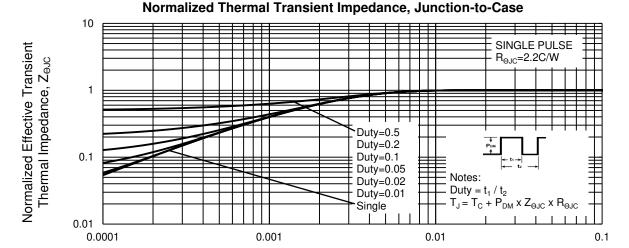




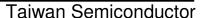
Maximum Safe Operating Area, Junction-to-Case





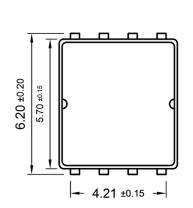


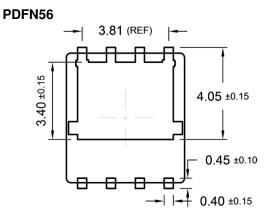
t, Square Wave Pulse Duration (sec)

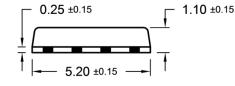


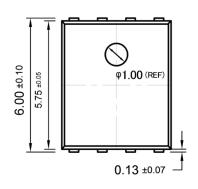


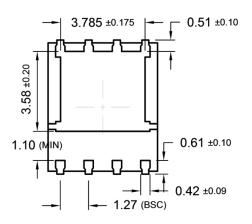
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

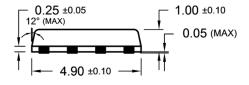




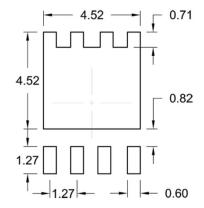




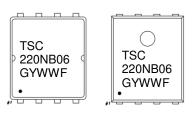




SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



G = Halogen Free

Y = Year Code

WW = Week Code (01~52)

F = Factory Code



Taiwan Semiconductor

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